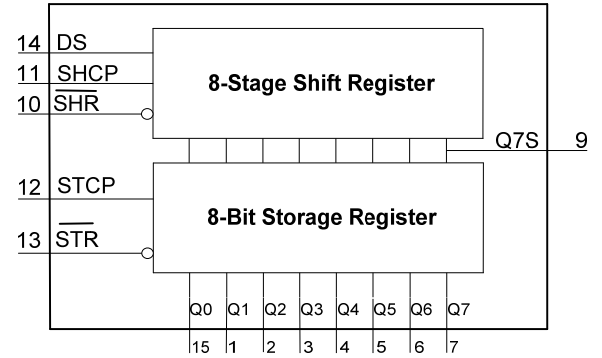


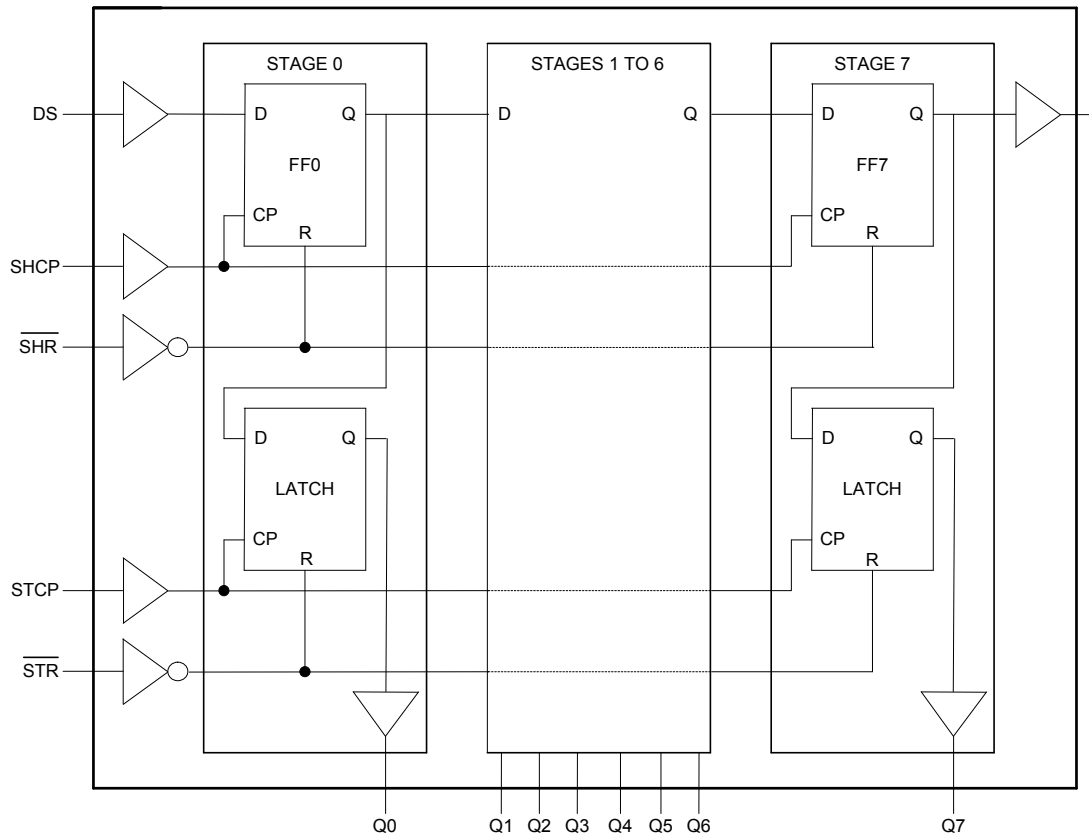
Pin Descriptions

Pin Number	Pin Name	Description
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	$\overline{\text{SHR}}$	Shift Register Reset active low
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	$\overline{\text{STR}}$	Storage Register Reset active low
14	DS	Serial Data Input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

Functional Diagram



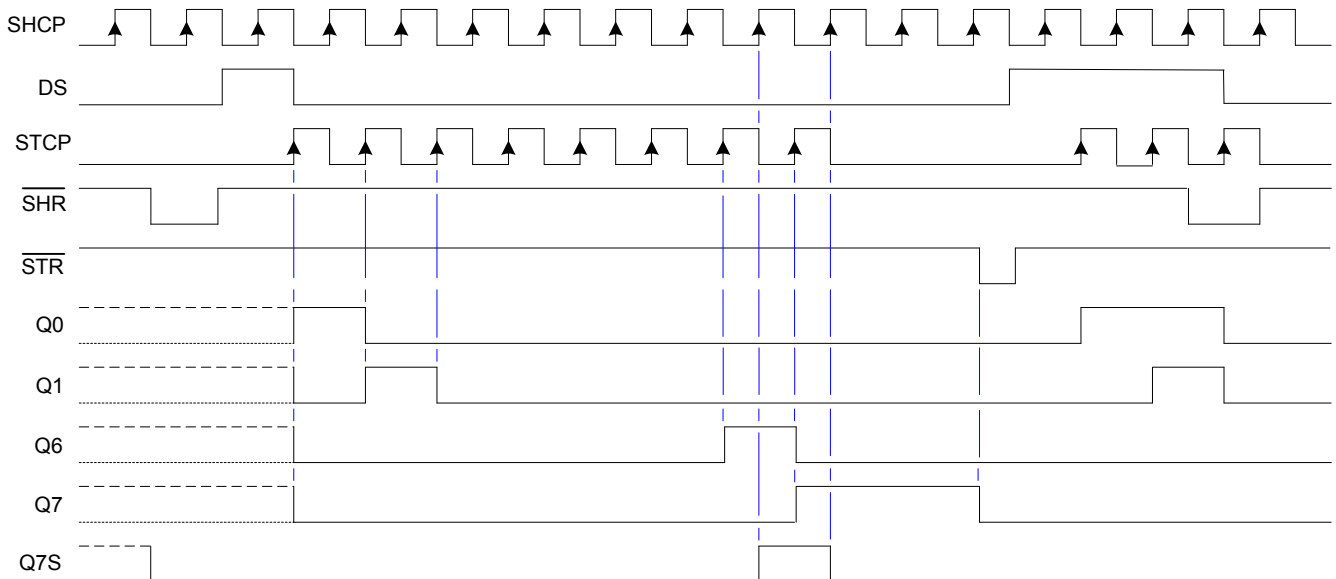
Logic Diagram



Functional Description and Timing Diagram

Control				Input	Output		Function
$\overline{\text{SHR}}$	$\overline{\text{STR}}$	SHCP	STCP	DS	Q7S	Qn	
L	X	X	X	X	L	NC	Clear Shift Register
X	L	X	X	X	NC	L	Clear Storage Register
H	X	↑	L	H or L	Q6S	NC	Loads DS into shift register stage 0. All Q_S shifted
H	H	X	↑	X	NC	Q_S	Contents of shift register moved to storage register all $Q_S \rightarrow Q_N$
H	H	↑	↑	H or L	Q6S	QnS	Shift Register one pulse count ahead of storage register.

H=HIGH voltage state
L=LOW voltage state
↑=LOW to HIGH transition
X= don't care – high or low (not floating)
NC= No change



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 7.0	V
V _I	Input Voltage Range	-0.5 to 7.0	V
V _O	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < -0.5V	-20	mA
I _{IK}	Input Clamp Current V _I > V _{CC} +0.5V	20	mA
I _{OK}	Output Clamp Current V _O < -0.5V	-20	mA
I _{OK}	Output Clamp Current V _O > V _{CC} + 0.5V	20	mA
I _O	Continuous output current	Q7 standard output	+/- 25
		Qn bus driver outputs	+/- 35
I _{CC}	Continuous current through V _{CC}	70	mA
I _{GND}	Continuous current through GND	-70	mA
T _J	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage	—	4.5	5.5	V
V _I	Input Voltage	—	0	5.5	V
V _O	Output Voltage	Active Mode	0	V _{CC}	V
Δt/ΔV	Input transition rise or fall rate	V _{CC} = 4.5V to 5.5V	—	500	ns/V
T _A	Operating free-air temperature	—	-40	+125	°C

Notes: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions		V _{CC}	T _A = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
					Min	Typ	Max	Min	Max	Min	Max	
V _{IH}	High-level Input Voltage	—		4.5 V to 5.5 V	2.0	1.6	—	2.0	—	2.0	—	V
V _{IL}	Low-level input voltage	—		4.5 V to 5.5 V	—	—	0.8	—	0.8	—	0.8	V
V _{OH}	High Level Output Voltage	I _{OH} = -20μA All outputs		4.5 V	4.4	4.5	—	4.4	—	4.4	—	V
	Q7S output	I _{OH} = -4.0mA		4.5 V	3.98	4.32	—	3.85	—	3.7	—	
	Qn Bus Outputs	I _{OH} = -6.0 mA		4.5 V	3.98	4.32	—	3.85	—	3.7	—	—
V _{OL}	Low-level Output Voltage	I _{OL} = 20μA All outputs		4.5 V	—	0	0.1	—	0.1	—	0.1	V
	Q7S output	I _{OL} = 4.0mA		4.5 V	—	0.15	0.26	—	0.33	—	0.4	
	Qn Bus Outputs	I _{OL} = 6.0mA		4.5 V	—	0.16	0.26	—	0.33	—	0.4	—
I _I	Input Current	V _I =GND to 5.5 V		5.5 V	—	—	±0.1	—	± 1	—	± 1	μA
I _{CC}	Supply Current	V _I = GND or V _{CC} I _O =0		5.5 V	—	—	8.0	—	80	—	160	μA
ΔI _{CC}	Additional Supply Current	Test Per Pin V _I = V _{CC} -2.1 V Other V _I = V _{CC} or GND I _O =0	PINS SHCP SHST SHR STR	4.5V to 5.5 V	—	100	240	—	300	—	300	μA
			PIN DS	4.5V to 5.5 V	—	75	120	—	150	—	150	
C _i	Input Capacitance	V _I = V _{CC} or GND	5.5 V	—	3.5	10	—	—	10	—	10	pF

Operating Characteristics

Parameter		Test Conditions	V _{CC} = 5V	Unit
			TYP	
C _{pd}	Power dissipation capacitance	f = 1 MHz all outputs switching-no load V _I = GND TO V _{CC} - 1.5V	51	pF

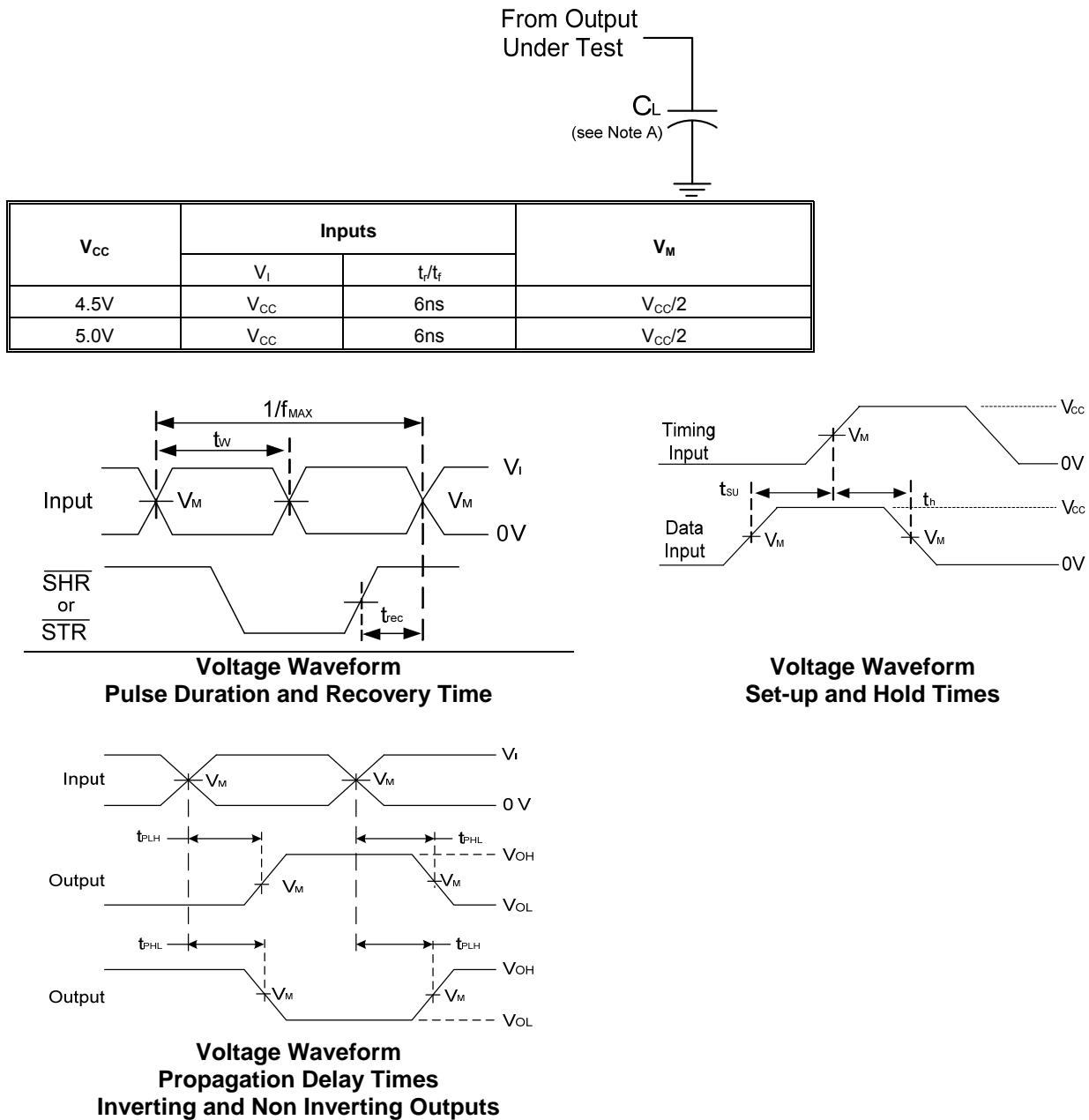
Switching Characteristics

Symbol / Parameter	Pins	Test Conditions	V _{CC}	T _A = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ.	Max	Min	Max	Min	Max	
f _{MAX} Maximum Frequency	SHCP or STCP	Figure 2 C _L =15pF	5.0 V	30	92	—	24	—	20	—	MHz
t _w Pulse Width	SHCP HIGH or LOW	Figure 2 C _L =50pF	4.5 V	16	4	—	20	—	24	—	ns
	STCP HIGH or LOW	Figure 2 C _L =50pF	4.5 V	16	4	—	20	—	24	—	
	SHR and STR HIGH or LOW	Figure 2 C _L =50pF	4.5 V	16	6	—	20	—	24	—	
t _{su} Set-up Time	DS to SHCP	Figure 2 C _L =50pF	4.5 V	20	4	—	25	—	30	—	ns
	SHR to STCP	Figure 2 C _L =50pF 2	4.5 V	20	6	—	25	—	30	—	
	SHCP to STCP	Figure 2 C _L =50pF	4.5 V	20	7	—	25	—	30	—	
t _{PD} Propagation Delay	SHCP to Q7S	Figure 2 C _L =50p	4.5 V	—	18	32	—	40	—	48	ns
		Figure 2 C _L =15pF	5.0 V	—	15	—	—	—	—	—	
	STCP to Qn	Figure 2 C _L =50p	4.5 V	—	18	32	—	40	—	48	
		Figure 2 C _L =15p	5.0 V	—	15	—	—	—	—	—	
t _H Hold Time	DS to SHCP	Figure 2	4.5 V	5	-3	—	6	—	7	—	ns
t _{REC} Recovery Time	SHR to SHCP and STR to STCP	Figure 2	4.5 V	10	-5	—	13	—	15	—	ns

Switching Characteristics (cont.)

Symbol / Parameter	Pins	Test Conditions	V_{CC}	$T_A = +25^{\circ}\text{C}$			$-40^{\circ}\text{C to } +85^{\circ}\text{C}$		$-40^{\circ}\text{C to } +125^{\circ}\text{C}$		Unit
				Min	Typ.	Max	Min	Max	Min	Max	
t_{PHL} Propagation Delay	$\overline{\text{SHR}}$ to Q7S	Figure 2 $C_L = 50\text{pF}$	4.5 V	–	17	30	–	38	–	45	ns
		Figure 2 $C_L = 15\text{pF}$	5.0 V	–	14	–	–	–	–	–	
	$\overline{\text{STR}}$ to Qn	Figure 2 $C_L = 50\text{pF}$	4.5 V	–	17	30	–	38	–	45	ns
		Figure 2 $C_L = 15\text{pF}$	5.0 V	–	14	–	–	–	–	–	
t_{THL} t_{TLH} Transition Times	Serial data output Q7S	Figure 2 $C_L = 50\text{pF}$	4.5 V	–	7	15	–	19	–	22	ns
	Parallel Data Outputs Q _N	Figure 2 $C_L = 50\text{pF}$	4.5 V	–	5	12	–	15	–	18	ns

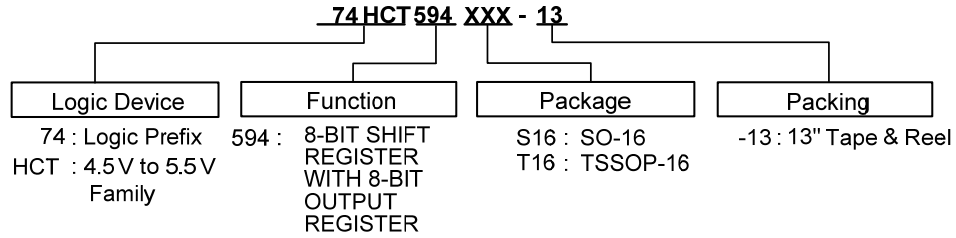
Parameter Measurement Information



- Notes:
- A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
 - C. Inputs are measured separately one transition per measurement
 - D. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 2. Load Circuit and Voltage Waveforms

Ordering Information

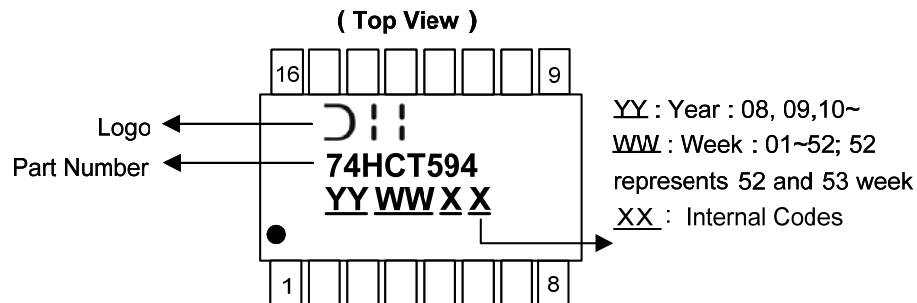


Device	Package Code	Packaging	7" Tape and Reel (Note 6)	
			Quantity	Part Number Suffix
74HCT594S16-13	S16	SO-16	2500/Tape & Reel	-13
74HCT594T16-13	T16	TSSOP-16	2500/Tape & Reel	-13

Notes: 6. The taping orientation is located on our website at <http://www.diodes.com/datasheets/ap02007.pdf>

Marking Information

(1) SO-16, TSSOP-16

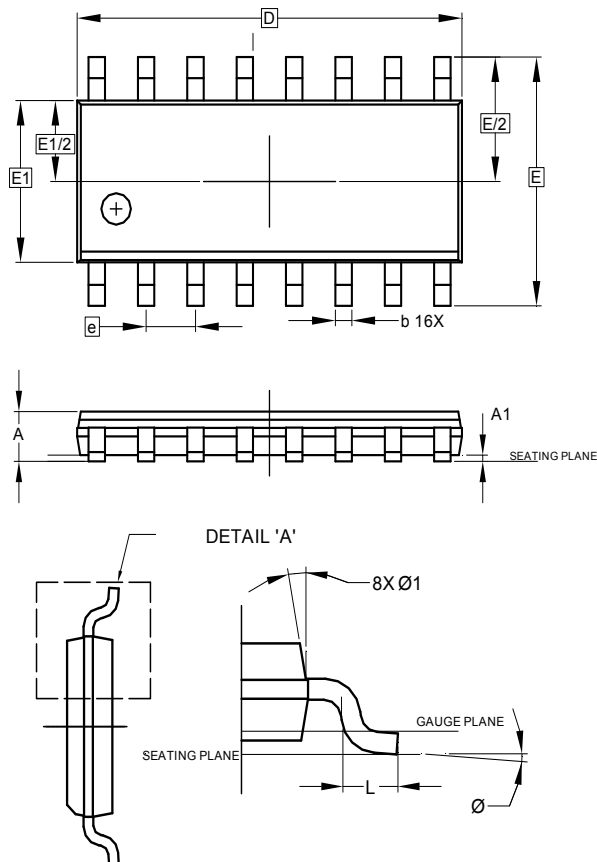


Part Number	Package
74HCT594S16	SO-16
74HCT594T16	TSSOP-16

Package Outline Dimensions (All Dimensions in mm.)

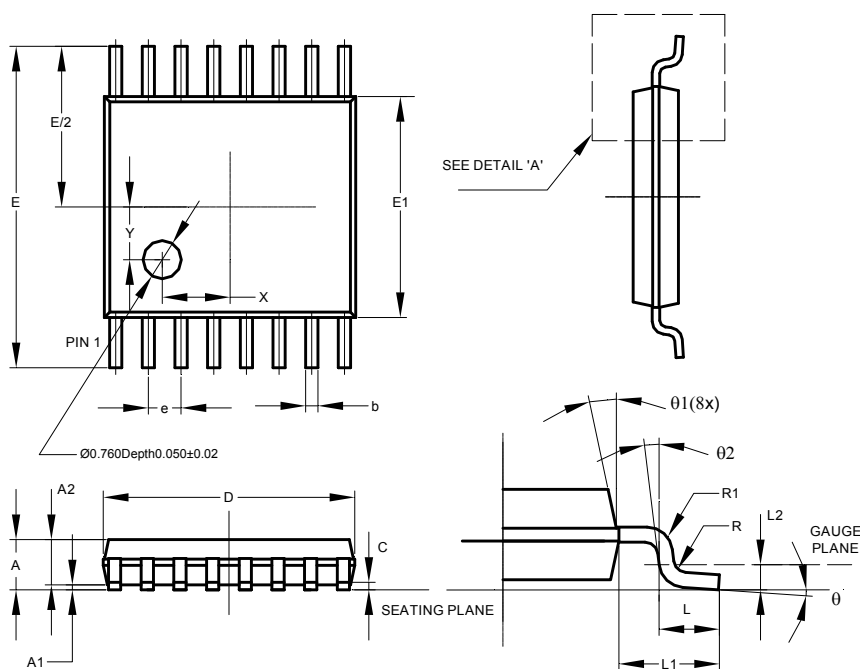
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

(1) Package Type: SO-16



SOIC-16			
Dim	Min	Max	Typ
A	—	1.75	—
A1	0.10	0.25	—
b	0.31	0.51	—
c	0.10	0.25	—
D	9.80	10.00	—
E	5.80	6.20	—
E1	3.80	4.00	—
e	—	—	1.27
L	0.40	1.27	—
Ø	0°	8°	—
Ø1	5°	15°	—
All Dimensions in mm			

(2) Package Type: TSSOP-16

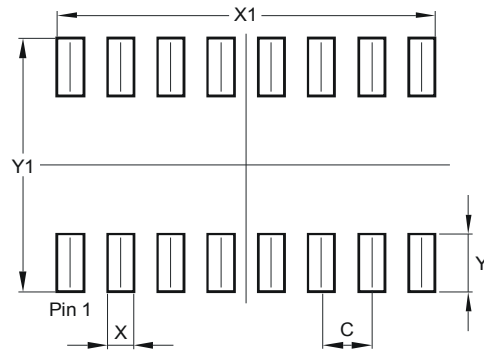


TSSOP-16			
Dim	Min	Max	Typ
A	—	1.08	—
A1	0.05	0.15	—
A2	0.80	0.93	—
b	0.19	0.30	—
c	0.09	0.20	—
D	4.90	5.10	—
E	6.40 BSC		
E1	4.30	4.50	—
e	0.65 BSC		
L	0.45	0.75	—
L1	1.00 REF		
L2	0.25 BSC		
R	0.09	—	—
R1	0.09	—	—
X	—	—	1.350
Y	—	—	1.050
Ø	0°	8°	—
Ø1	5°	15°	—
Ø2	0°	—	—
All Dimensions in mm			

Suggested Pad Layout

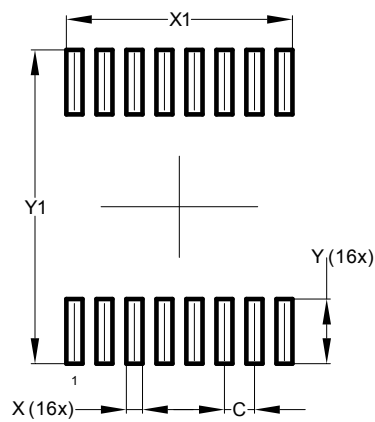
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)
C	1.270
X	0.670
X1	9.560
Y	1.450
Y1	6.400

Package Type: TSSOP-16



Dimensions	Value (in mm)
C	0.650
X	0.350
X1	4.900
Y	1.400
Y1	6.800

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